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TPS54239E

ZHCSAQ8-JANUARY 2013

具有 Eco-Mode™ 的 4.5V 至 23V 输入, 2A 同步降压 SWIFT™ 转换器

查询样品: TPS54239E

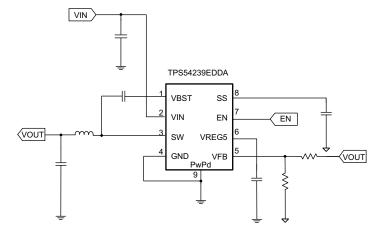
说明

特性

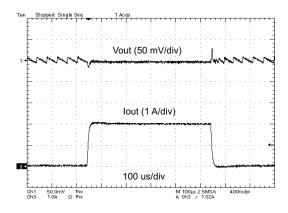
- D-CAP2™ 模式支持快速瞬态响应
- 低输出纹波,支持陶瓷输出电容器
- 宽泛的 V_{IN}输入电压范围: 4.5V 至 23V
- 输出电压范围: 0.76V 至 7.0V
- 高效率集成型场效应晶体管 (FET) 针对更低占空比应用进行了优化
 -140mΩ(高侧)与 70mΩ(低侧)
- 关断时的高效率,流耗不足 10µA
- 初始带隙参考的高精度
- 可调软启动
- 预偏置软启动
- 600kHz 开关频率 (f_{sw})
- 逐周期限流
- 自动跳跃 Eco-mode[™] 为了在轻负载下实现高效率

应用范围

- 低电压系统的广泛应用
 - 数字电视电源
 - 高清 Blu-ray Disc[™] 播放器
 - 网络家庭终端设备
 - 数字机顶盒 (STB)



TPS54239E 是一款自适应接通时间 D-CAP2™ 模式同 步降压转换器。TPS54239E 可帮助系统设计人员通过 一个低成本、低组件数、低待机电流解决方案来完成各 种终端设备电源总线调节器集。 TPS54239E 的主控制 环路采用 D-CAP2™ 模式控制,无需外部补偿组件便 可实现极快的瞬态响应。自适应接通时间控制支持较 高负载状态下的脉宽调制 (PWM) 模式与轻负载下的 Eco-mode™ 工作模式之间的无缝转换。 Eco-mode™ 使 TPS54239 能够在较轻负载条件下保持高效率。 TPS54239E 的专有电路还有助于该器件适应诸如高分 子有机半导体固体电容器 (POSCAP) 或特种聚合物电 容器 (SP-CAP) 等低等效串联电阻 (ESR) 输出电容器 以及超低 ESR 陶瓷电容器。 该器件的工作输入电压介 于 4.5V 至 23V VIN 输入之间。 输出电压可在 0.76V 与 7V 之间进行设定。此外,该器件还特有一个可调软 启动时间。 TPS54239E 采用 8 引脚 DDA 封装,并针 对 -40℃ 到 85℃ 的工作温度范围内的运行而设计。



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ^{(2) (3)}	ORDERABLE PART NUMBER	PIN	TRANSPORT MEDIA
40°C to 05°C		TPS54239EDDA	0	Tube
–40°C to 85°C	DDA	TPS54239EDDAR	8	Tape and Reel

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) All package options have Cu NIPDAU lead/ball finish.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		VAI		
		MIN	UNIT	
	VIN, EN	-0.3	25	
	VBST	-0.3	31	
	VBST (10 ns transient)	-0.3	33	
Input voltage range	VBST (vs SW)	-0.3	6.5	V
	VFB, SS	-0.3	6.5	
	SW	-2	25	
	SW (10 ns transient)	-3	27	
	VREG5	-0.3	6.5	V
Output voltage range	GND	-0.3	0.3	V
Voltage from GND to thermal	pad, V _{diff}	-0.2	0.2	V
Electrostatic discharge	Human Body Model (HBM)		2	kV
Electrostatic discharge	Charged Device Model (CDM)		500	V
Operating junction temperatur	e, T _J	-40	150	.
Storage temperature, T _{stg}		-55	150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL INFORMATION

	THERMAL METRIC ⁽¹⁾	TPS54239E	
		DDA (8 PINS)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	46.2	
θ _{JCtop}	Junction-to-case (top) thermal resistance	53.9	
θ_{JB}	Junction-to-board thermal resistance	29.7	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	10.0	C/W
Ψ_{JB}	Junction-to-board characterization parameter	29.6	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	6.6	

(1) 有关传统和新的热度量的更多信息,请参阅/C 封装热度量应用报告, SPRA953。



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RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range, (unless otherwise noted)

			MIN	MAX	UNIT
V _{IN}	Supply input voltage range		4.5	23	V
		VBST	-0.1	29	
		VBST (10 ns transient)	-0.1	32	
		VBST(vs SW)	-0.1	5.7	
		SS	-0.1	5.7	
VI	Input voltage range	EN	-0.1	23	V
		VFB	-0.1	5.5	
		SW	-1.8	23	
		SW (10 ns transient)	-3	26	
		GND	-0.1	0.1	
Vo	Output voltage range	VREG5	-0.1	5.7	V
I _O	Output Current range	I _{VREG5}	0	10	mA
T _A	Operating free-air temperature		-40	85	°C
TJ	Operating junction temperature		-40	150	°C

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range, V_{IN} = 12 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
SUPPLY	CURRENT						
I _{VIN}	Operating - non-switching supply current	V_{IN} current, $T_A = 25^{\circ}C$, EN = 5V, $V_{FB} = 0.8V$		600	1100	μA	
IVINSDN	Shutdown supply current	V_{IN} current, $T_A = 25^{\circ}C$, $EN = 0 V$		3.0	10	μA	
LOGIC TH	IRESHOLD						
V _{ENH}	EN high-level input voltage	EN	1.6			V	
V _{ENL}	EN low-level input voltage	EN			0.6	V	
R _{EN}	EN pin resistance to GND	V _{EN} = 12 V	200	400	800	kΩ	
V _{FB} VOLT	AGE AND DISCHARGE RESISTANCE	•	-				
N/		$T_A = 25^{\circ}C, V_O = 1.05 V, I_O = 10 mA,$ Eco-mode TM operation		772		mV	
V _{fbth}	V _{FB} threshold voltage	$T_A = 25^{\circ}C$, $V_O = 1.05$ V, continuous mode operation	749	765	781	mV	
I _{VFB}	V _{FB} input current	V _{FB} = 0.8 V, T _A = 25°C		0	±0.1	μA	
V _{REG5} OU	TPUT	•	- <u>i</u>				
V _{VREG5}	V _{REG5} output voltage	$T_A = 25^{\circ}C, 6.0 V < V_{IN} < 23 V,$ 0 < I _{VREG5} < 5 mA	5.2	5.5	5.7	V	
I _{VREG5}	Output current	V _{IN} = 6 V, V _{REG5} = 4.0 V, T _A = 25°C	20			mA	
MOSFET		L					
R _{DS(on)h}	High side switch resistance	25°C, V _{BST} - SW = 5.5 V ⁽¹⁾		140		mΩ	
R _{DS(on)I}	Low side switch resistance	25°C ⁽¹⁾		70		mΩ	
CURREN							
I _{ocl}	Current limit	L out = 2.2 μ H ⁽¹⁾	2.5	3.1	4.6	А	
THERMAI	L SHUTDOWN						
-		Shutdown temperature ⁽¹⁾		165		•••	
T _{SDN}	Thermal shutdown threshold	Hysteresis ⁽¹⁾		40		°C	
ON-TIME	TIMER CONTROL						
t _{ON}	On time	V _{IN} = 12 V, V _O = 1.05 V		160		ns	
t _{OFF(MIN)}	Minimum off time	$T_A = 25^{\circ}C, V_{FB} = 0.7 V^{(1)}$		260	310	ns	

(1) Not production tested.

TEXAS INSTRUMENTS

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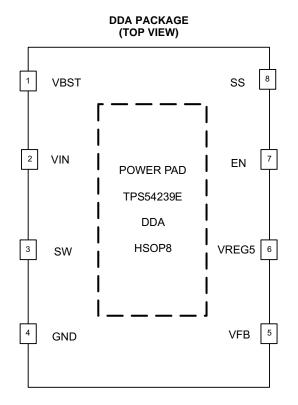
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ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range, $V_{IN} = 12$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT				
SOFT START										
I _{SSC}	SS charge current	V _{SS} = 1.0 V	4.2	6.0	7.8	μA				
I _{SSD}	SS discharge current	V _{SS} = 0.5 V	0.8	1.5		mA				
HICCUP /	AND OVERVOLTAGE PROTECTION		÷							
V _{OVP}	Output OVP threshold	OVP Detect (L>H)		125%						
V _{UVP}	Output Hiccup threshold	Hiccup detect (H>L)		65%						
TUVPDEL	Output Hiccup delay	to Hiccup state		6		μs				
T _{UVPEN}	Output Hiccup Enable delay	Relative to soft-start time		x1.7						
UVLO			÷							
		Wake up V _{REG5} voltage	3.45	3.75	4.05	Ň				
UVLO	UVLO threshold	Hysteresis V _{REG5} voltage	0.17	0.17 0.33 0.		V				

DEVICE INFORMATION



PIN FUNCTIONS

PIN		DESCRIPTION
NAME	NO.	DESCRIPTION
VBST	1	Supply input for the high-side FET gate drive circuit. Connect 0.1µF capacitor between VBST and SW pins. An internal diode is connected between VREG5 and VBST.
VIN	2	Input voltage supply pin.
SW	3	Switch node connection between high-side NFET and low-side NFET.
GND	4	Ground pin. Power ground return for switching circuit. Connect sensitive SS and VFB returns to GND at a single point.
VFB	5	Converter feedback input. Connect to output voltage with feedback resistor divider.



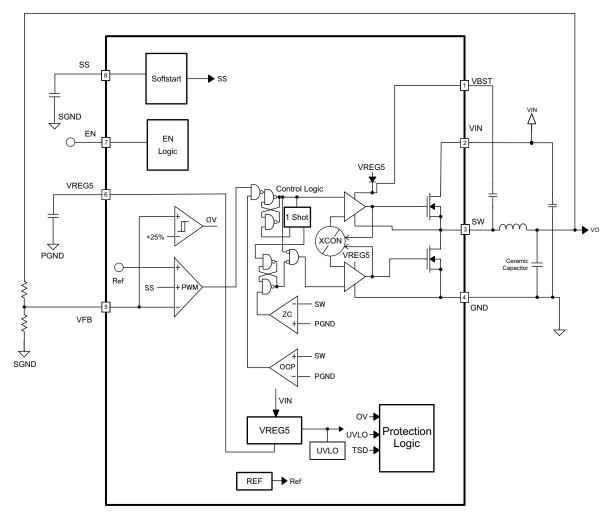
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PIN FUNCTIONS (continued)

PIN		DESCRIPTION
NAME	NO.	DESCRIPTION
VREG5	6	5.5 V power supply output. A capacitor (typical 0.47 $\mu F)$ should be connected to GND. VREG5 is not active when EN is low.
EN	7	Enable input control. EN is active high and must be pulled up to enable the device.
SS	8	Soft-start control. An external capacitor should be connected to GND.
Exposed Thermal Pad	Back side	Thermal pad of the package. Must be soldered to achieve appropriate dissipation. Must be connected to GND.



FUNCTIONAL BLOCK DIAGRAM

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OVERVIEW

The TPS54239E is a 2-A synchronous step-down (buck) converter with two integrated N-channel MOSFETs. It operates using D-CAP2[™] mode control. The fast transient response of D-CAP2[™] control reduces the output capacitance required to meet a specific level of performance. Proprietary internal circuitry allows the use of low ESR output capacitors including ceramic and special polymer types.

DETAILED DESCRIPTION

PWM Operation

The main control loop of the TPS54239E is an adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2[™] mode control. D-CAP2[™] mode control combines constant on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one shot timer expires. This one shot is set by the converter input voltage, VIN, and the output voltage, VO, to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An internal ramp is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2[™] mode control.

PWM Frequency and Adaptive On-Time Control

TPS54239E uses an adaptive on-time control scheme and does not have a dedicated on board oscillator. The TPS54239E runs with a pseudo-constant frequency of 600 kHz by using the input voltage and output voltage to set the on-time one-shot timer. The on-time is inversely proportional to the input voltage and proportional to the output voltage; therefore, when the duty ratio is VOUT/VIN, the frequency is constant.

Auto-Skip Eco-Mode™ Control

The TPS54239E is designed with Auto-Skip Eco-modeTM to increase light load efficiency. As the output current decreases from heavy load condition, the inductor current is also reduced and eventually comes to point that its rippled valley touches zero level, which is the boundary between continuous conduction and discontinuous conduction modes. The rectifying MOSFET is turned off when its zero inductor current is detected. As the load current further decreases the converter run into discontinuous conduction mode. The on-time is kept almost the same as is was in the continuous conduction mode so that it takes longer time to discharge the output capacitor with smaller load current to the level of the reference voltage. The transition point to the light load operation $I_{OUT(LL)}$ current can be calculated in Equation 1

$$I_{OUT(LL)} = \frac{1}{2 \cdot L \cdot fsw} \cdot \frac{(V_{IN} - V_{OUT}) \cdot V_{OUT}}{V_{IN}}$$
(1)

Soft Start and Pre-Biased Soft Start

The soft start function is adjustable. When the EN pin becomes high, 6 μ A current begins charging the capacitor which is connected from the SS pin to GND. Smooth control of the output voltage is maintained during start up. The equation for the slow start time is shown in Equation 2. VFB voltage is 0.765 V and SS pin source current is 6 μ A.

$$t_{SS}(ms) = \frac{C_{SS}(nF) \times V_{REF} \times 1.1}{I_{SS}(\mu A)} = \frac{C_{SS}(nF) \times 0.765 \times 1.1}{6}$$
(2)

The TPS54239E contains a unique circuit to prevent current from being pulled from the output during startup if the output is pre-biased. When the soft-start commands a voltage higher than the pre-bias level (internal soft start becomes greater than feedback voltage V_{FB}), the controller slowly activates synchronous rectification by starting the first low side FET gate driver pulses with a narrow on-time. It then increments that on-time on a cycle-by-cycle basis until it coincides with the time dictated by (1-D), where D is the duty cycle of the converter. This scheme prevents the initial sinking of the pre-bias output, and ensure that the out voltage (V_O) starts and ramps up smoothly into regulation and the control loop is given time to transition from pre-biased start-up to normal mode operation.



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Current Protection

The output overcurrent protection (OCP) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored by measuring the low-side FET switch voltage between the SW pin and GND. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated.

During the on time of the high-side FET switch, the switch current increases at a linear rate determined by V_{IN} , V_{OUT} , the on-time and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current lout. The TPS54239E constantly monitors the low-side FET switch voltage, which is proportional to the switch current, during the low-side on-time. If the measured voltage is above the voltage proportional to the current limit, an internal counter is incremented per each SW cycle and the converter maintains the low-side switch on until the measured voltage is below the voltage corresponding to the current limit at which time the switching cycle is terminated and a new switching cycle begins. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner. If the over current condition exists for 7 consecutive switching cycles, the internal OCL threshold is set to a lower level, reducing the available output current. When a switching cycle occurs where the switch current is not above the lower OCL threshold, the counter is reset and the OCL limit is returned to the higher value.

There are some important considerations for this type of over-current protection. The load current one half of the peak-to-peak inductor current higher than the over-current threshold. Also when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. This may cause the output voltage to fall. When the VFB voltage becomes lower than 65% of the target voltage, the UVP comparator detects it. After 6µs detecting the UVP voltage, device will shut down and restart after 7 times SS period for Hiccup.

When the over current condition is removed, the output voltage returns to the regulated value. This protection is non-latching.

Over Voltage Protection

TPS54239E detects over voltage conditions by monitoring the feedback voltage (VFB). This function is enabled after approximately 1.7 x times the soft start time.

When the feedback voltage becomes higher than 125% of the target voltage, the OVP comparator output goes high and both the high-side MOSFET driver and the low-side MOSFET driver turn off. This function is non-latch operation.

UVLO Protection

Undervoltage lock out protection (UVLO) monitors the voltage of the V_{REG5} pin. When the V_{REG5} voltage is lower than UVLO threshold voltage, the TPS54239E is shut off. This protection is non-latching.

Thermal Shutdown

TPS54239E monitors the temperature of itself. If the temperature exceeds the threshold value (typically 165°C), the device is shut off. This is non-latch protection.

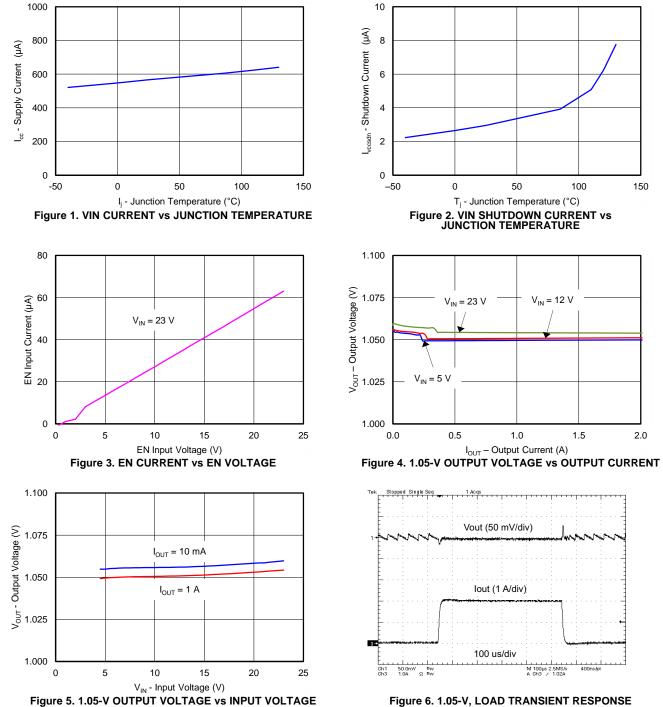
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TYPICAL CHARACTERISTICS

VIN = 12 V, $T_A = 25^{\circ}C$ (unless otherwise noted).







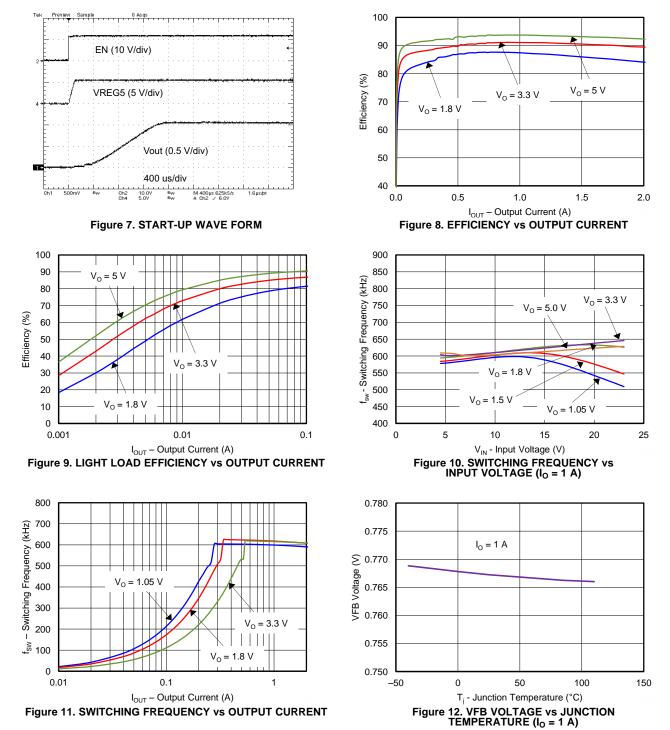
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TYPICAL CHARACTERISTICS

VIN = 12 V, $T_A = 25^{\circ}C$ (unless otherwise noted).



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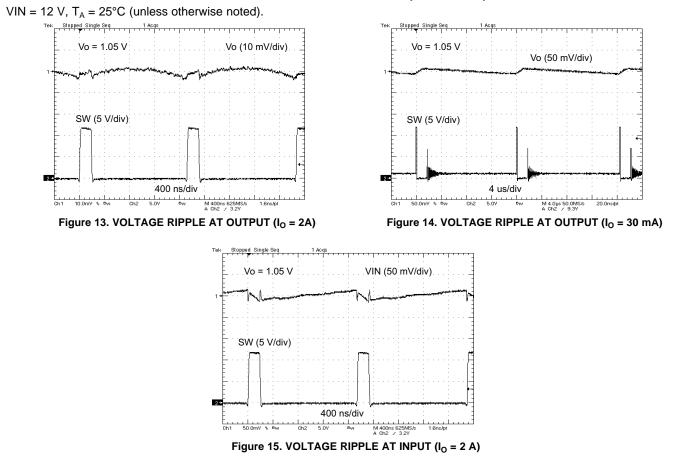
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NSTRUMENTS

EXAS

TYPICAL CHARACTERISTICS (continued)





DESIGN GUIDE

Step-By-Step Design Procedure

To begin the design process, the user must know a few application parameters:

- Input voltage range
- Output voltage
- Output current
- Output voltage ripple
- Input voltage ripple

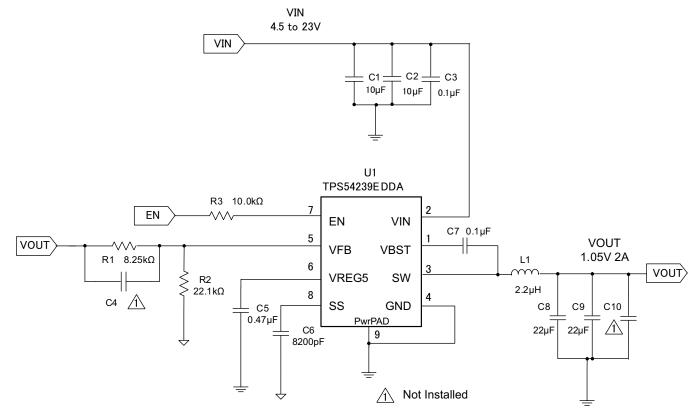


Figure 16. Shows the schematic diagram for this design example.

Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB pin. It is recommended to use 1% tolerance or better divider resistors. Start by using Equation 3 to calculate V_{OUT} .

To improve efficiency at light loads consider using larger value resistors, high resistance is more susceptible to noise, and the voltage errors from the VFB input current are more noticeable.

$$V_{OUT} = 0.765 \text{ x} \left(1 + \frac{\text{R1}}{\text{R2}} \right)$$

Output Filter Selection

The output filter used with the TPS54239E is an LC circuit. This LC filter has double pole at:

$$F_{\rm P} = \frac{1}{2\pi \sqrt{L_{\rm OUT} \times C_{\rm OUT}}}$$
(4)

(3)

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At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the TPS54239E. The low frequency phase is 180 degrees. At the output filter pole frequency, the gain rolls off at a -40 dB per decade rate and the phase drops rapidly. D-CAP2[™] introduces a high frequency zero that reduces the gain roll off to -20 dB per decade and increases the phase to 90 degrees one decade above the zero frequency. The inductor and capacitor selected for the output filter must be selected so that the double pole of Equation 4 is located below the high frequency zero but close enough that the phase boost provided be the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in Table 1

Output				C4 (pF) ⁽¹⁾			L1 (µH)		C8 + C9 +	- C10 (μF)
Voltage R1 (V)	R1 (kΩ)	R2 (kΩ)	Min	Тур	Max	Min	Тур	Max	Min	Max
1	6.81	22.1	5	150	220	1.5	2.2	4.7	22	68
1.05	8.25	22.1	5	150	220	1.5	2.2	4.7	22	68
1.2	12.7	22.1	5		100	1.5	2.2	4.7	22	68
1.5	21.5	22.1	5		68	1.5	2.2	4.7	22	68
1.8	30.1	22.1	5		22	2.2	3.3	4.7	22	68
2.5	49.9	22.1	5		22	2.2	3.3	4.7	22	68
3.3	73.2	22.1	5		22	2.2	3.3	4.7	22	68
5	124	22.1	5		22	3.3		4.7	22	68
6.5	165	22.1	5		22	3.3		4.7	22	68

Table 1	Recommended	Component	Values
---------	-------------	-----------	--------

(1) Optional

Since the DC gain is dependent on the output voltage, the required inductor value increases as the output voltage increases. Additional phase boost can be achieved by adding a feed forward capacitor (C4) in parallel with R1. The amount of available phase boost is dependent on the output voltage. Higher output voltages will allow greater phase boost.

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 5. Equation 6 and Equation 7. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current. Use 600 kHz for f_{SW}.

Use 600 kHz for f_{sw}. Make sure the chosen inductor is rated for the peak current of Equation 6 and the RMS current of Equation 7.

$II_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}}$	(5)
$II_{PEAK} = I_{O} + \frac{II_{P-P}}{2}$	(6)
$I_{LO(RMS)} = \sqrt{I_0^2 + \frac{1}{12}I_{P-P}^2}$	(7)

For this design example, the calculated peak current is 2.38 A and the calculated RMS current is 2.01 A. The inductor used is a TDK CLF7045T-2R2N with a peak current rating of 5.5 A and an RMS current rating of 4.3 A. For high current designs, TDK SPM6530T-4R7M 4.7µH is also recommended. The SPM6530 series has a higher current rating than the CLF7045 series.

The capacitor value and ESR determines the amount of output voltage ripple. The TPS54239E is intended for use with ceramic or other low ESR capacitors. Recommended values range from 22µF to 68µF. Use Equation 8 to determine the required RMS current rating for the output capacitor.

$$I_{Co(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_{O} \times f_{SW}}$$

(8)

(7)

For this design two TDK C3216X5R0J226M 22μF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.22 A and each output capacitor is rated for 4A.



Input Capacitor Selection

The TPS54239E requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 μ F is recommended for the decoupling capacitor. An additional 0.1 μ F capacitor from pin 2 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

Bootstrap Capacitor Selection

A 0.1 μ F. ceramic capacitor must be connected between the VBST to SW pin for proper operation. It is recommended to use a ceramic capacitor.

VREG5 Capacitor Selection

A 0.47 µF. ceramic capacitor must be connected between the VREG5 to GND pin for proper operation. It is recommended to use a ceramic capacitor.

THERMAL INFORMATION

This 8-pin DDA package incorporates an exposed thermal pad that is designed to be directly to an external heartsick. The thermal pad must be soldered directly to the printed board (PCB). After soldering, the PCB can be used as a heartsick. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heartsick structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the exposed thermal pad and how to use the advantage of its heat dissipating abilities, see the Technical Brief, PowerPAD[™] Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD[™] Made Easy, Texas Instruments Literature No. SLMA004.

The exposed thermal pad dimensions for this package are shown in the following illustration.

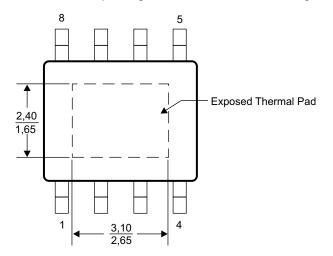


Figure 17. Thermal Pad Dimensions

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LAYOUT CONSIDERATIONS

- 1. Keep the input switching current loop as small as possible.
- 2. Keep the SW node as physically small and short as possible to minimize parasitic capacitance and inductance and to minimize radiated emissions. Kelvin connections should be brought from the output to the feedback pin of the device.
- 3. Keep analog and non-switching components away from switching components.
- 4. Make a single point connection from the analog ground to power ground.
- 5. Do not allow switching current to flow under the device.
- 6. Keep the pattern lines for VIN and PGND broad.
- 7. Exposed pad of device must be connected to PGND with solder.
- 8. VREG5 capacitor should be placed near the device, and connected to PGND.
- 9. Output capacitor should be connected to a broad pattern of the PGND.
- 10. Voltage feedback loop should be as short as possible, and preferably with ground shield.
- 11. Lower resistor of the voltage divider which is connected to the VFB pin should be tied to analog ground trace.
- 12. Providing sufficient via is preferable for VIN, SW and PGND connection.
- 13. VIN input bypass capacitor and VIN high frequency bypass capacitor must be placed as near as possible to the device.
- 14. Performance based on four layer printed circuit board.

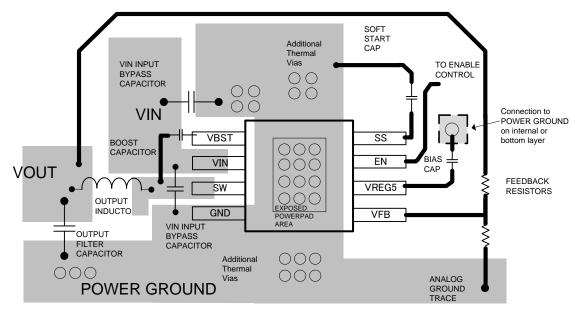


Figure 18. PCB Layout

Instruments

Texas



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS54239EDDA	ACTIVE	SO PowerPAD	DDA	8	75	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 85	54239E	Samples
TPS54239EDDAR	ACTIVE	SO PowerPAD	DDA	8	2500	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 85	54239E	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

GENERIC PACKAGE VIEW

DDA 8

PowerPAD[™] SOIC - 1.7 mm max height PLASTIC SMALL OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



DDA0008B



PACKAGE OUTLINE

PowerPAD[™] SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MS-012.



DDA0008B

EXAMPLE BOARD LAYOUT

PowerPAD[™] SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



DDA0008B

EXAMPLE STENCIL DESIGN

PowerPAD[™] SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



DDA (R-PDSO-G8)

PowerPAD ™ PLASTIC SMALL-OUTLINE



- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.



DDA (R-PDSO-G8)

PowerPAD[™] PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD^{\mathbb{N}} package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206322-6/L 05/12

NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments



DDA (R-PDSO-G8)

PowerPAD[™] PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads. PowerPAD is a trademark of Texas Instruments.



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